

# BCR12PM-12LD

600V - 12A - Triac  
Medium Power Use

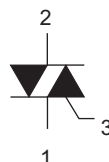
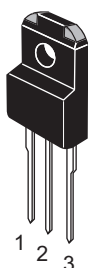
R07DS0973EJ0100  
Rev.1.00  
Dec 20, 2012

## Features

- $I_{T(RMS)}$ : 12 A
- $V_{DRM}$ : 600 V
- $I_{FGTI}$ ,  $I_{RGTI}$ ,  $I_{RGTHI}$ : 50 mA
- $V_{iso}$ : 2000 V
- $T_j$ : 150 °C
- Insulated Type
- Planar Passivation Type
- UL Recognized: File No. E223904

## Outline

RENESAS Package code: PRSS0003AA-A  
(Package name: TO-220F )



1.  $T_1$  Terminal
2.  $T_2$  Terminal
3. Gate Terminal

## Applications

Heater control, motor control

## Maximum Ratings

Parameter	Symbol	Voltage class	
		12	Unit
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	600	V
Non-repetitive peak off-state voltage <sup>Note1</sup>	$V_{DSM}$	700	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T(RMS)}$	12	A	Commercial frequency, sine full wave 360° conduction, $T_c = 77^\circ\text{C}$
Surge on-state current	$I_{TSM}$	72	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
$I^2t$ for fusion	$I^2t$	21.6	$\text{A}^2\text{s}$	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	5	W	
Average gate power dissipation	$P_{G(AV)}$	0.5	W	
Peak gate voltage	$V_{GM}$	10	V	
Peak gate current	$I_{GM}$	2	A	
Junction Temperature	$T_j$	-40 to +150	°C	
Storage temperature	$T_{stg}$	-40 to +150	°C	
Mass	—	2.0	g	Typical value
Isolation voltage <sup>Note5</sup>	$V_{iso}$	2000	V	$T_a = 25^\circ\text{C}$ , AC 1 minute, $T_1 \bullet T_2 \bullet G$ terminal to case

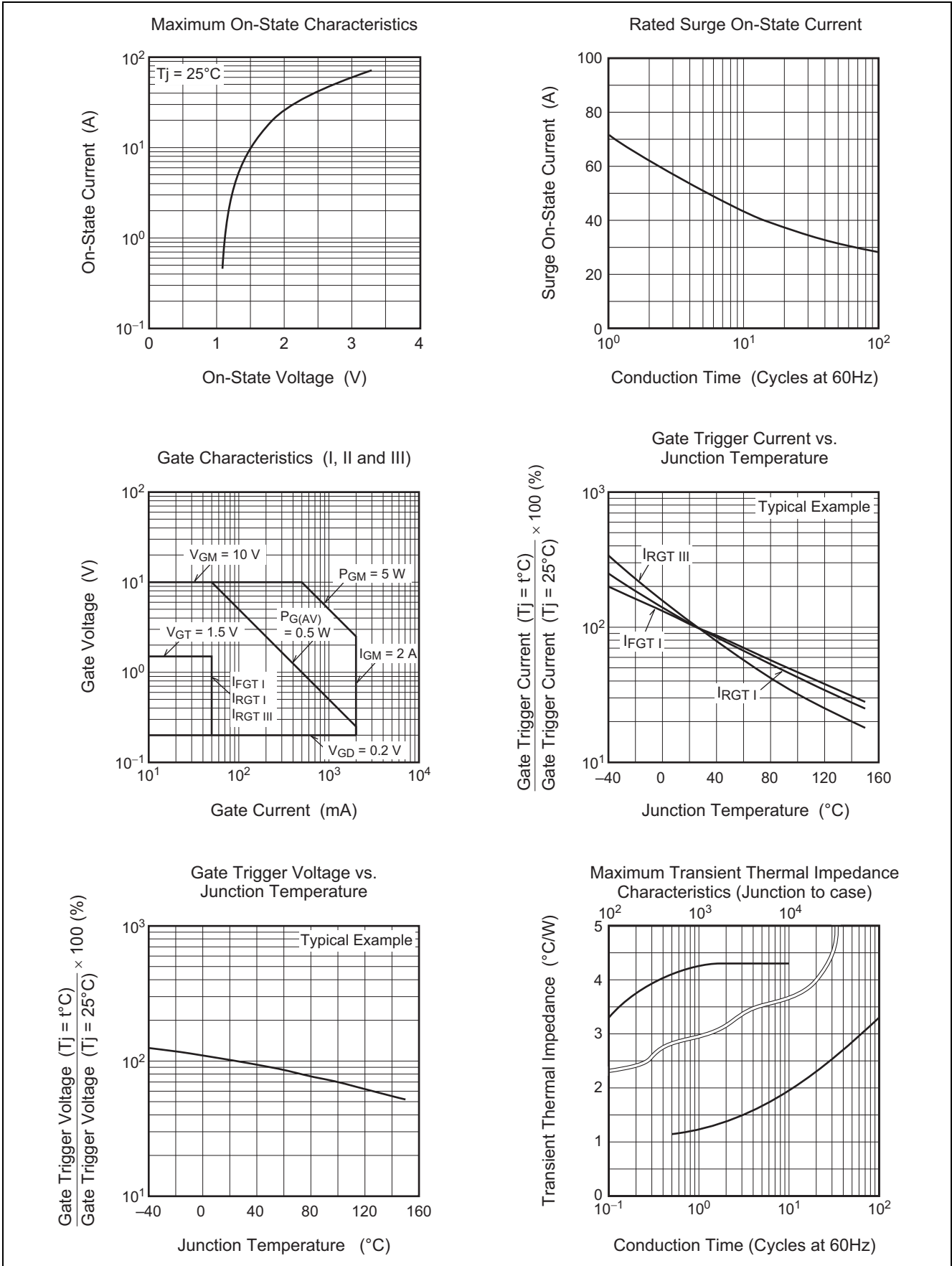
## Electrical Characteristics

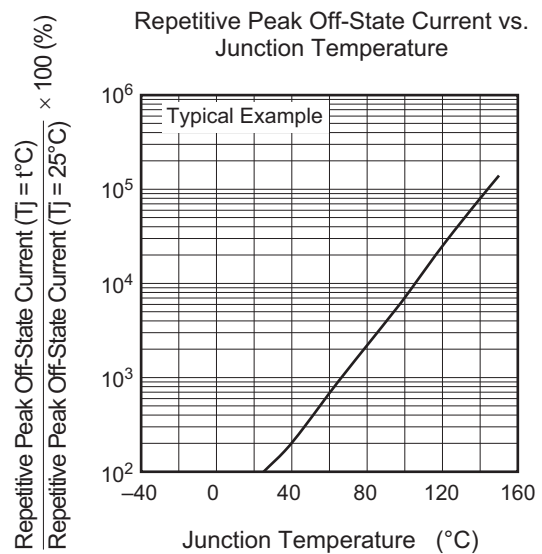
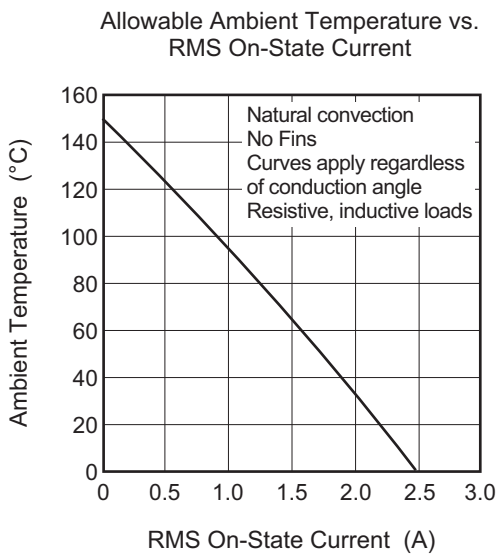
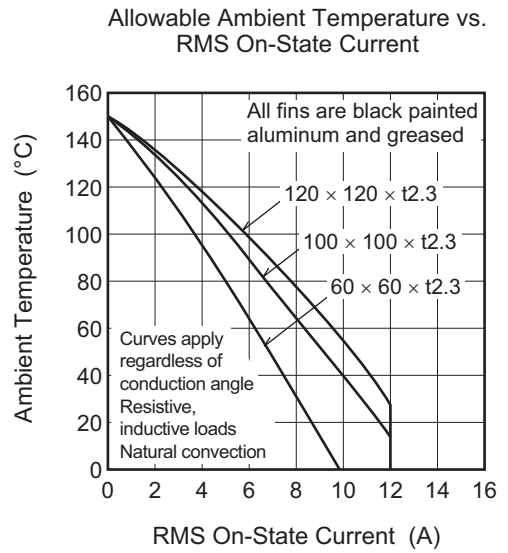
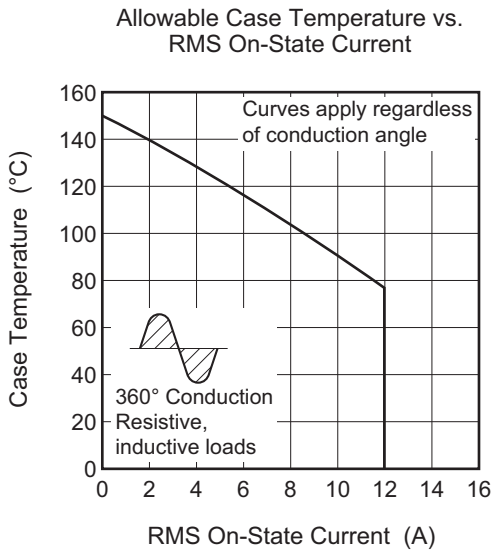
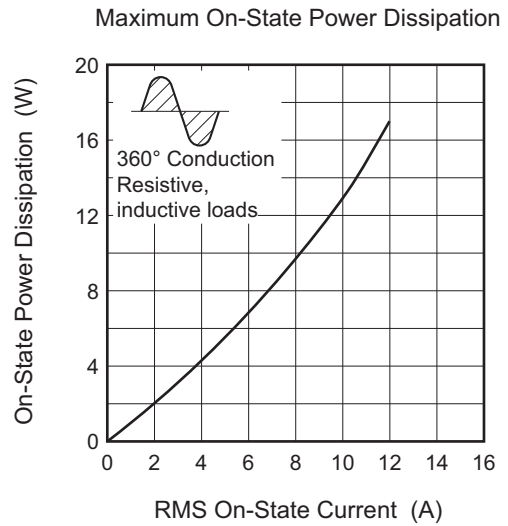
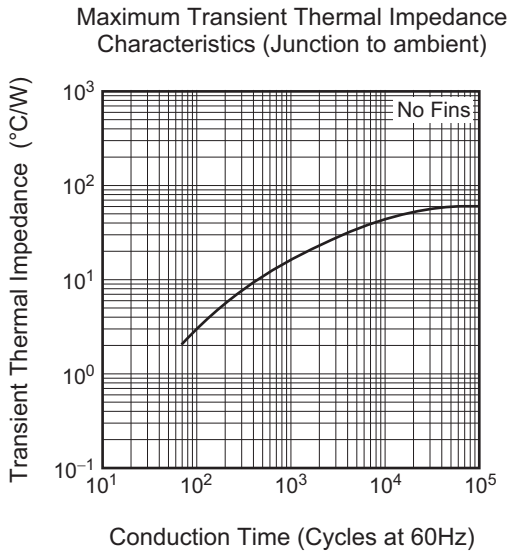
Parameter	Symbol	Rated value			Unit	Test conditions
		Min.	Typ.	Max.		
Repetitive peak off-state current	$I_{DRM}$	—	—	2.0	mA	$T_j = 150^\circ\text{C}$ , $V_{DRM}$ applied
On-state voltage	$V_{TM}$	—	—	1.8	V	$T_c = 25^\circ\text{C}$ , $I_{TM} = 20\text{A}$ , instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	I	$V_{FGTI}$	—	—	1.5	$T_j = 25^\circ\text{C}$ , $V_D = 6\text{V}$ , $R_L = 6\ \Omega$ , $R_G = 330\ \Omega$
	II	$V_{RGTI}$	—	—	1.5	
	III	$V_{RGTIII}$	—	—	1.5	
Gate trigger current <sup>Note2</sup>	I	$I_{FGTI}$	—	—	50	$T_j = 25^\circ\text{C}$ , $V_D = 6\text{V}$ , $R_L = 6\ \Omega$ , $R_G = 330\ \Omega$
	II	$I_{RGTI}$	—	—	50	
	III	$I_{RGTIII}$	—	—	50	
Gate non-trigger voltage	$V_{GD}$	0.2	—	—	V	$T_j = 125^\circ\text{C}$ , $V_D = 1/2 V_{DRM}$
Thermal resistance	$R_{th(j-c)}$	—	—	4.3	$^\circ\text{C}/\text{W}$	Junction to case <sup>Note3</sup>
Critical-rate of rise of off-state commutation voltage <sup>Note4</sup>	$(dv/dt)_c$	10	—	—	$\text{V}/\mu\text{s}$	$T_j = 125^\circ\text{C}$

- Notes: 1. Gate open.  
 2. Measurement using the gate trigger characteristics measurement circuit.  
 3. The contact thermal resistance  $R_{th(c-f)}$  in case of greasing is  $0.5^\circ\text{C}/\text{W}$ .  
 4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.  
 5. Make sure that your finished product containing this device meets your safe isolation requirements.  
 For safety, it's advisable that heatsink is electrically floating.

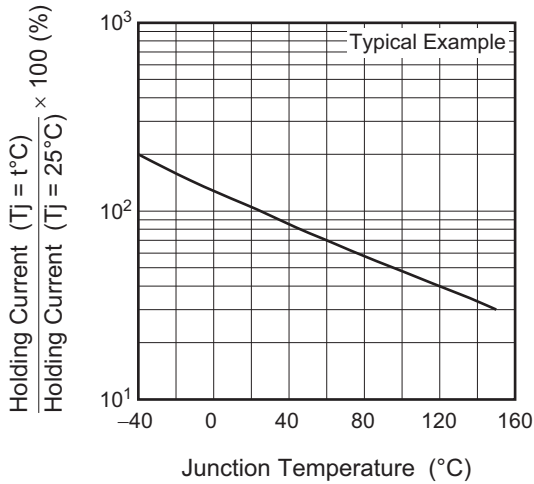
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j = 125^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c = -6\text{ A/ms}$ 3. Peak off-state voltage $V_D = 400\text{ V}$	

Main Characteristics

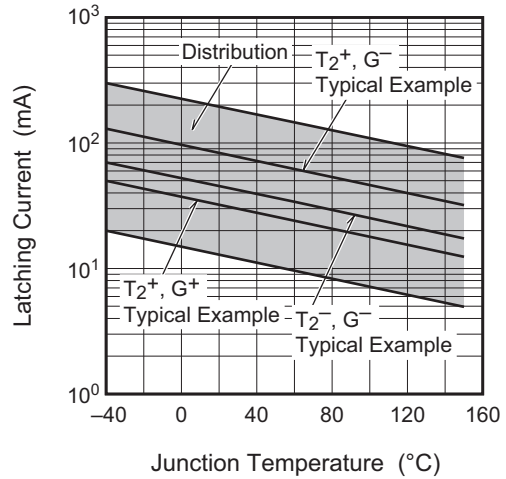




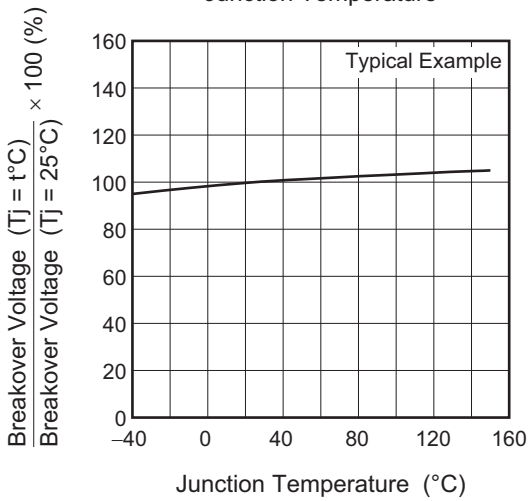
Holding Current vs. Junction Temperature



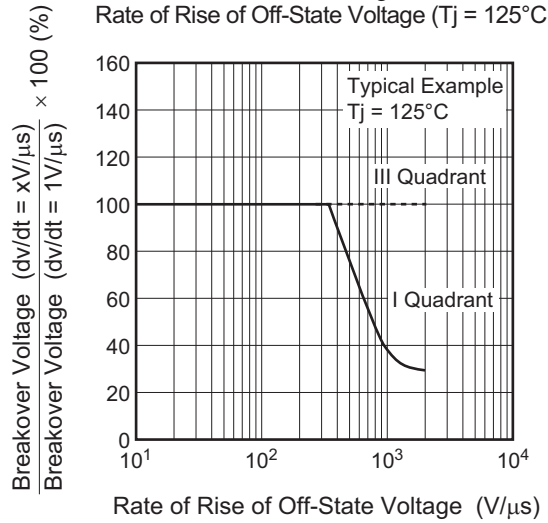
Latching Current vs. Junction Temperature



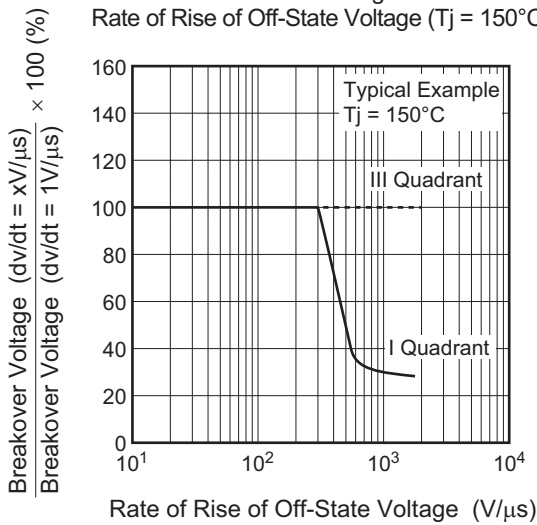
Breakover Voltage vs. Junction Temperature



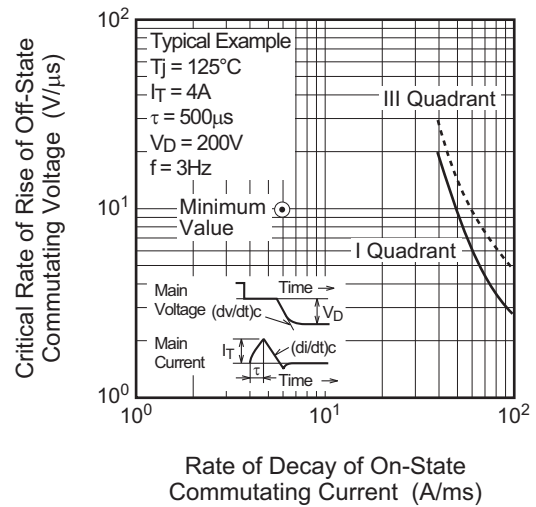
Breakover Voltage vs. Rate of Rise of Off-State Voltage (Tj = 125°C)

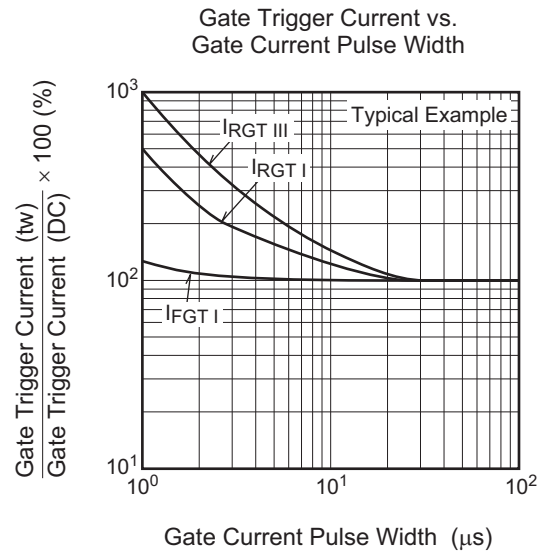
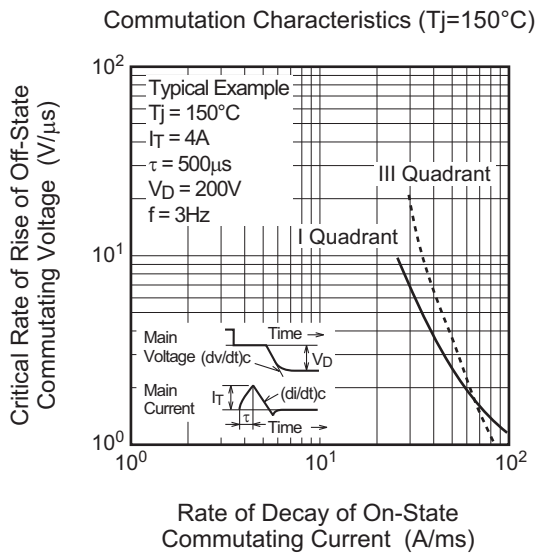


Breakover Voltage vs. Rate of Rise of Off-State Voltage (Tj = 150°C)

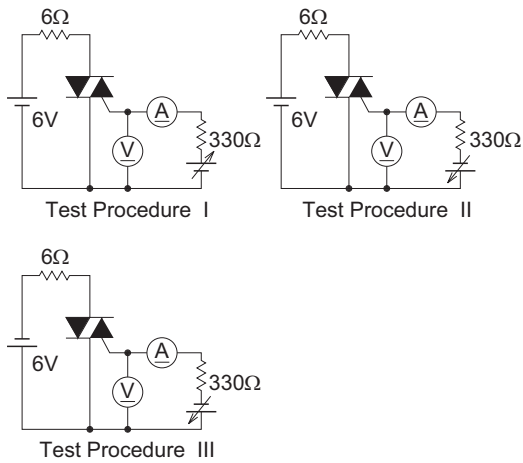


Commutation Characteristics (Tj=125°C)





Gate Trigger Characteristics Test Circuits



## Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	Unit: mm
TO-220F	SC-67	PRSS0003AA-A	T220F	2.0g	

The drawing shows the following dimensions:

- Top view: Total width 10.5Max, central hole diameter 5.2, distance from hole to edge 1.2, hole diameter  $\phi 3.2 \pm 0.2$ .
- Side view: Total height 17, distance from top to hole 5.0, distance from hole to lead start 8.5, lead length 13.5Min, lead thickness 0.8, lead width 1.3Max, lead spacing 2.54, lead diameter 0.5, lead length to tip 2.6, and lead tip diameter 2.8.
- Detail view: Lead width 4.5.

## Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR12PM-12LD#B00	Bag	100 pcs.	Straight type
BCR12PM-12LDA8#B00	Tube	50 pcs.	A8 Lead form

Note: Please confirm the specification about the shipping in detail.

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